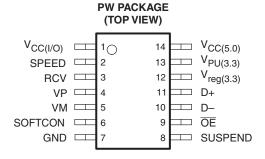
#### **FEATURES**

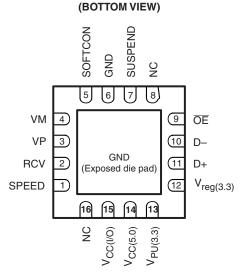
- Complies With Universal Serial Bus Specification Rev. 2.0 (USB 2.0)
- Transmits and Receives Serial Data at Both Full-Speed (12-Mbit/s) and Low-Speed (1.5-Mbit/s) Data Rates
- Integrated Bypassable 5-V to 3.3-V Voltage Regulator for Powering Via USB VBUS
- Low-Power Operation, Ideal for Portable Equipment
- Meets the IEC-61000-4-2 Contact (±9KV) and Air-gap (±9KV) ESD Ratings
- Separate I/O Supply With Operation Down to 1.65 V
- Very-Low Power Consumption to Meet USB Suspend Current Requirements
- No Power-Supply Sequencing Requirements

#### **APPLICATIONS**

- Cellular Phones
- Personal Digital Assistants (PDAs)
- Handheld Computers



**RGT PACKAGE** 



NC - No internal connection

#### **DESCRIPTION/ORDERING INFORMATION**

The TUSB2551 is a single-chip transceiver that complies with the physical-layer specifications of universal serial bus (USB) 2.0. The device supports both full-speed (12-Mbit/s) and low-speed (1.5-Mbit/s) operation. The TUSB2551 delivers superior edge rate control, producing crisper eye diagrams, which ease the task of passing USB compliance testing.

A dual supply-voltage operation allows the TUSB2551 to reference the system interface I/O signals to a supply voltage down to 1.6 V, while independently powered by the USB  $V_{CC(5.0)}$ . This allows the system interface to operate at its core voltage without the addition of buffering logic, and also reduce system operating current.

#### ORDERING INFORMATION

T <sub>A</sub>	PACKAGE <sup>(1)(2)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING	
-40°C to 85°C	QFN – RGT	Reel of 2000	TUSB2551RGTR	ZWT	
	TSSOP - PW	Reel of 3000	TUSB2551PWR	TU2551	

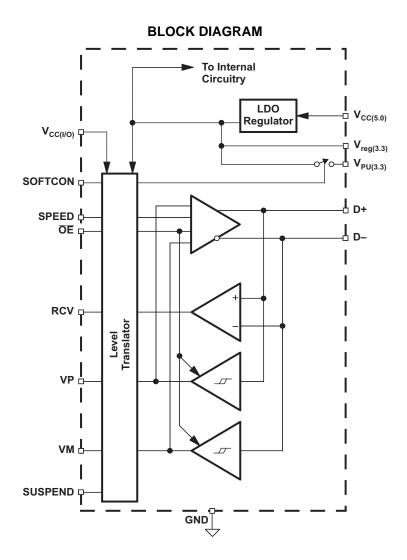
(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





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#### **TERMINAL FUNCTIONS**

Т	ERMINAL	RMINAL		
NAME	RGT NO.	PW NO.	I/O	DESCRIPTION
V <sub>CC(I/O)</sub>	15	1	ı	System interface supply voltage. Used to provide reference supply voltage for system I/O interface signaling.
SPEED	1	2	ı	Speed. Edge-rate control: A logic HIGH operates at edge rates for full-speed operation. A logic LOW operates at edge rates for low-speed operation.
RCV	2	3	0	Receive data. Output for USB differential data.
VP	3	4	I/O	If $\overline{OE} = 1$ , VP = Receiver output (+) If $\overline{OE} = 0$ , VP = Driver input (+)
VM	4	5	I/O	If $\overline{OE} = 1$ , VM = Receiver output (–) If $\overline{OE} = 0$ , VM = Driver input (–)
SOFTCON	5	6	I	Soft connect. Controls state of $V_{PU(3.3)}$ . Refer to $V_{PU(3.3)}$ pin description for details.
GND	6	7		Ground reference
SUSPEND	7	8	I	Suspend. Active high. Turns off internal circuits to reduce supply current.
NC	8, 16			No internal connection
ŌĒ	9	9	ı	Output enable. Active low. Enables the transceiver to transmit data onto the bus. When inactive, the transceiver is in the receive mode.
D-, D+	10, 11	10, 11	I/O	Differential data lines conforming to the USB standard
V <sub>reg(3.3)</sub>	12	12	0	3.3-V reference supply. Requires a minimum 0.1- $\mu$ F decoupling capacitor for stability. A 1- $\mu$ F capacitor is recommended.
V <sub>PU(3.3)</sub>	13	13	0	Pullup supply voltage. Used to connect 1.5-k $\Omega$ pullup speed detect resistor. If SOFTCON = 1, $V_{PU(3.3)}$ is high impedance. If SOFTCON = 0, $V_{PU(3.3)}$ = 3.3 V.
V <sub>CC(5.0)</sub>	14	14	I	USB bus supply voltage. Used to power USB transceiver and internal circuitry.

### **FUNCTIONAL DESCRIPTION**

#### **FUNCTION SELECTION**

SUSPEND	ŌĒ	D+, D-	RCV	VP, VM	FUNCTION
0	0	Driving	Active	Active	Normal transmit mode
0	1	Receiving	Active	Active	Normal receive mode
1	0	Hi-Z	0	Not active	Low power state
1	1	Hi-Z	0	Active	Receiving during suspend (low power state) <sup>(1)</sup>

<sup>(1)</sup> During suspend, VP and VM are active in order to detect out-of-band signaling conditions.

#### TRUTH TABLE DURING NORMAL MODE

OE = 0					
INPUT			OUTPUT		RESULT
VP	VM	D+	D-	RCV	RESULI
0	0	0	0	X <sup>(1)</sup>	SE0
0	1	0	1	0	Logic 0
1	0	1	0	1	Logic 1
1	1	1	1	X <sup>(1)</sup>	Undefined
<u>OE</u> = 1					
lnı	put		RESULT		
D+	D-	VP	VM	RCV	RESULI
0	0	0	0	X <sup>(1)</sup>	SE0
0	1	0	1	0	Logic 0
1	0	1	0	1	Logic 1
1	1	1	1	X <sup>(1)</sup>	Undefined

(1) X = Undefined



#### **Power-Supply Configurations**

The TUSB2551 can be used with different power-supply configurations, which can be dynamically changed. An overview is given in Table 1.

- Normal mode Both V<sub>CC(I/O)</sub> and V<sub>CC(5.0)</sub> or V<sub>CC(5.0)</sub> and V<sub>reg(3.3)</sub> are connected. For 5-V operation, V<sub>CC(5.0)</sub> is connected to a 5-V source (4 V to 5.5 V). The internal voltage regulator then produces 3.3 V for the USB connections. For 3.3-V operation, both V<sub>CC(5.0)</sub> and V<sub>reg(3.3)</sub> are connected to a 3.3-V source (3 V to 3.6 V). V<sub>CC(I/O)</sub> is independently connected to a voltage source (1.65 V to 3.6 V), depending on the supply voltage of the external circuit.
- Disable mode V<sub>CC(I/O)</sub> is not connected; V<sub>CC(5.0)</sub> or V<sub>CC(5.0)</sub> and V<sub>reg(3.3)</sub> are connected. In this mode, the internal circuits of the TUSB2551 ensure that the D+ and D- pins are in 3-state, and the power consumption drops to the low-power (suspended) state level. Some hysteresis is built into the detection of V<sub>CC(I/O)</sub> lost.
- Sharing mode  $V_{CC(I/O)}$  is connected;  $V_{CC(5.0)}$  and  $V_{reg(3.3)}$  are not connected. In this mode, the D+ and D-pins are made 3-state, and the TUSB2551 allows external signals of up to 3.6 V to share the D+ and D-lines. The internal circuits of the TUSB2551 ensure that virtually no current (maximum 10 mA) is drawn via the D+ and D- lines. The power consumption through  $V_{CC(I/O)}$  drops to the low-power (suspended) state level. Both the VP and VM pins are driven HIGH to indicate this mode. Pin RCV is made LOW. Some hysteresis is built into the detection of  $V_{reg(3.3)}$  lost.

**Table 1. Power-Supply Configuration Overview** 

Configuration Mode	VBUS/VTRM	VIF	Notes
Normal	Connected	Connected	Normal supply configuration and operation.
Disconnect (D+/D- sharing)	Open	Connected	VP/VM are HIGH outputs, RCV is LOW. With OE# = 0 and SUSPEND = 1, data lines may be driven with external devices up to 3.6 V. With D+, D– floating, I <sub>CC(I/O)</sub> draws less than 1 μA.
Disconnect	Ground	Connected	VP/VM are HIGH outputs, RCV is LOW. With D+, D– floating, $I_{CC(I/O)F}$ draws less than 1 $\mu$ A.
Disable Mode	Connected	Open	Logic controlled inputs pins are Hi-Z
Prohibited	Connected	Ground	Prohibited condition

Table 2. Pin States in Disable or Sharing Mode

PINS	DISABLE-MODE STATE	SHARING-MODE STATE
V <sub>CC(5.0)</sub> /V <sub>reg(3.3)</sub>	5-V input/3.3-V output, 3.3-V input/3.3-V input	Not present
V <sub>CC(I/O)</sub>	Not present	1.65-V to 3.6-V input
V <sub>PU(3.3)</sub>	High impedance (off)	High impedance (off)
D+, D-	High impedance	High impedance
VP, VM	Invalid <sup>(1)</sup>	Н
RCV	Invalid <sup>(1)</sup>	L
Inputs (SPEED, SUSPEND, OE, SOFTCON)	High impedance	High impedance

(1) High impedance or driven LOW

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### **Power-Supply Input Options**

The TUSB2551 has two power-supply input options.

- Internal regulator V<sub>CC(5.0)</sub> is connected to 4 V to 5.5 V. The internal regulator is used to supply the internal circuitry with 3.3 V (nominal). V<sub>reg(3.3)</sub> becomes a 3.3-V output reference.
- Regulator bypass  $V_{CC(5.0)}$  and  $V_{reg(3.3)}$  are connected to the same supply. The internal regulator is bypassed, and the internal circuitry is supplied directly from the  $V_{reg(3.3)}$  power supply. The voltage range is 3 V to 3.6 V to comply with the USB specification.

The supply-voltage range for each input option is specified in Table 3.

#### **Table 3. Power-Supply Input Options**

INPUT OPTION V <sub>CC(5.0)</sub>		V <sub>reg(3.3)</sub>	V <sub>CC(I/O)</sub>
Internal regualtor	Supply input for internal regulator (4 V to 5.5 V)	Voltage-reference output (3.3 V, 300 μA)	Supply input for digital I/O pins (1.4 V to 3.6 V)
Regulator bypass	Connected to V <sub>reg(3.3)</sub> with maximum voltage drop of 0.3 V (2.7 V to 3.6 V)	Supply input (3 V to 3.6 V)	Supply input for digital I/O pins (1.4 V to 3.6 V)

## **Electrostatic Discharge (ESD)**

PIN NAME	ESD	TYP	UNIT
D+, D-, V <sub>CC(5.0)</sub>	IEC61000-4-2, Air-Gap Discharge	±9	
	IEC61000-4-2, Contact Discharge	±9	kV
	Human-Body Model	±15	
All other pins	Human-Body Model	±2	kV

Product Folder Link(s): TUSB2551

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### ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V <sub>CC(5.0)</sub>	Supply voltage range	-0.5	6	V
V <sub>CC(I/O)</sub>	I/O supply voltage range	-0.5	4.6	V
$V_{reg(3.3)}$	Regulated voltage range	-0.5	4.6	V
$V_{I}$	DC input voltage range	-0.5	$V_{CC(I/O)} + 0.5$	mA
I <sub>O(D+, D-)</sub>	Output Current (D+, D-)		±50	mA
Io	Output Current (all others)		±15	mA
I	Input Current		±50	mA
T <sub>stg</sub>	Storage temperature range	-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## **RECOMMENDED OPERATING CONDITIONS**

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>CC(5.0)</sub>	Supply voltage, internal regulator option	5-V operation	4	5	5.25	V
$V_{reg(3.3)}$	Supply voltage, regulator bypass option	3.3-V operation	3	3.3	3.6	V
V <sub>CC(I/O)</sub>	I/O supply voltage		1.65		3.6	V
$V_{IL}$	Low-level input voltage <sup>(1)</sup>		V <sub>CC(I/O)</sub> -0.3		0.15 V <sub>CC(I/O)</sub>	V
V <sub>IH</sub>	High-level input voltage <sup>(1)</sup>		0.85 V <sub>CC(I/O)</sub>		$V_{CC(I/O)} + 0.3$	V
D+, D-	Input voltage on analog I/O pins		0		3.6	V
T <sub>c</sub>	Junction temperature range		-40		85	°C

<sup>(1)</sup> Specification applies to the following pins: SUSPEND, SPEED, RCV, SOFTCON, VP, VM,  $\overline{\text{OE}}$ 

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## DC ELECTRICAL CHARACTERISTICS SYSTEM AND USB INTERFACE<sup>(1)</sup>

 $V_{CC(I/O)} = 3.6 \text{ V}, V_{CC(5.0)} = 5 \text{ V}$  (unless otherwise noted),  $T_A = 25$  C. Bold indicates specifications over temperature,  $-40^{\circ}\text{C}$  to

Р	PARAMETER		TES	T CONE	DITIONS		MIN	TYP	MAX	UNIT
V <sub>OH</sub>	High-level output voltage (2)	I <sub>OH</sub> = 20 μ	I <sub>OH</sub> = 20 μA							V
V <sub>OL</sub>	Low-level output voltage <sup>(2)</sup>	I <sub>OL</sub> = 20 μA							0.1	V
I <sub>IL</sub>	Input leakage current <sup>(2)</sup>						<b>-</b> 5	1.5	5	μΑ
		SPEED	SUSPEND	ΟE	VOLTAGE	LOAD				
		1	0	1				1	5	
		1	0	0				1	5	
		0	0	1				1	5	μΑ
I <sub>CC(I/O)</sub>	V <sub>CC(I/O)</sub> supply current	0	0	0	V <sub>CC(5.0)</sub> = 5.25 V,			1	5	
33(1,3)		0	1	0	$V_{CC(I/O)} =$			1	5	
		1	0	0	3.6 V	f = 6 MHz, C <sub>L</sub> = 50 pF		1	2	mA
		0	0	0		f = 750 kHz, C <sub>L</sub> = 600 pF		260	280	μΑ
		1	0	1	V <sub>CC(5.0)</sub> = 5.25 V,			800	1100	
		1	0	0				3000	5000	μΑ
		0	0	1				230	350	
		0	0	0				400	700	
I <sub>CC(5.0)</sub>	V <sub>CC(5.0)</sub> supply current	0	1	0	$V_{CC(I/O)} =$			130	200	
		1	0	0	3.6 V	f = 6 MHz, C <sub>L</sub> = 50 pF		6	10	
		0	0	0		f = 750 kHz, C <sub>L</sub> = 600 pF		43	5	mA
I <sub>PU(3.3)LEAK</sub>	V <sub>PU(3.3)</sub> leakage current	SOFTCOM	$V = 1, V_{PU(3.3)}$	= 0 V		-	<b>–</b> 5	1 5 1 5 1 5 1 5 1 5 1 5 1 5 1 2 n 260 280 µ 800 1100 3000 5000 230 350 400 700 130 200 6 10 43 5 -5 5 µ -5 5 µ 3 3.3 3.6	μΑ	
I <sub>CC(I/O)LEAK</sub>	V <sub>CC(I/O)</sub> leakage current		3.6 V, V <sub>CC(5.0</sub>				<b>-</b> 5		5	μΑ
V <sub>PU(3.3)</sub>	Pullup output voltage	. ,	200 μA, V <sub>CC(5.</sub>		to 5.25 V		3	3.3	3.6	V
R <sub>SW</sub>	V <sub>PU(3.3)</sub> switch resistance	J( )	0 mA, V <sub>CC(5.0</sub>					10		Ω
ESD PROTEC	CTION	1							L	
IEC-61000-4-	Air-Gap Discharge	10 pulses						±9		
2 (D+, D-, V <sub>CC(5.0)</sub> only)	Contact Discharge	10 pulses						±9		kV

Specification for packaged product only Specification applies to the following pins: RCV, VP, VM,  $\overline{\text{OE}}$ .

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## DC ELECTRICAL CHARACTERISTICS TRANSCEIVER<sup>(1)</sup>

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
LEAKAC	GE CURRENT		•		'	
I <sub>LO</sub>	Hi-Z state data line leakage (suspend mode)	0 V < V <sub>IN</sub> < 3.3 V, SUSPEND = 1	-10		10	μΑ
INPUT L	EVELS					
V <sub>DI</sub>	Differential input sensitivity	(D+) - (D-)	0.2			V
V <sub>CM</sub>	Differential common mode range	Includes V <sub>DI</sub> range	0.8		2.5	V
V <sub>SE</sub>	Single-ended receiver threshold		0.8		2	V
	Receiver hysteresis			200		mV
OUTPUT	Γ LEVELS					
V <sub>OL</sub>	Static output low	$R_L = 1.5 \text{ k}\Omega \text{ to } 3.6 \text{ V}$			0.3	V
V <sub>OH</sub>	Static output high	$R_L = 15 \text{ k}\Omega \text{ to GND}$	2.8		3.6	V
CAPACI	TANCE				,	
C <sub>IN</sub>	Transceiver capacitance	Pin to GND		10		pF
Z <sub>DRV</sub>	Driver output resistance	Steady-state drive	1	6	11	Ω

<sup>(1)</sup> Specification for packaged product only



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# AC ELECTRICAL CHARACTERISTICS(1)

	PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT					
DRIVER CHARACTERISTICS (LOW SPEED)										
T <sub>R</sub>	Transition rise time	$C_L$ = 200 pF, See Figure 2 $C_L$ = 600 pF	75	300	ns					
T <sub>F</sub>	Transition fall time	$C_L$ = 200 pF, See Figure 2 $C_L$ = 600 pF	75	300	ns					
LRFM	Rise/fall time matching	$T_R$ , $T_F$	80	125	%					
$V_{CRS}$	Output signal crossover voltage		1.3	2	V					
DRIVE	R CHARACTERISTICS (FULL SPEED)									
T <sub>R</sub>	Transition rise time	C <sub>L</sub> = 50 pF, See Figure 2	4	20	ns					
T <sub>F</sub>	Transition fall time	C <sub>L</sub> = 50 pF, Figure 2	4	20	ns					
FRFM	Rise/fall time matching	(TR, TF)	90	111.1	%					
V <sub>CRS</sub>	Output signal crossover voltage		1.3	2	V					
TRANS	CEIVER TIMING (FULL SPEED)									
t <sub>PVZ</sub>	OE to receiver 3-state delay	See Figure 1		15	ns					
t <sub>PZD</sub>	Receiver 3-state to transmit delay	See Figure 1	15		ns					
t <sub>PDZ</sub>	OE to driver 3-state delay	See Figure 1		15	ns					
t <sub>PZV</sub>	Driver 3-state to receive delay	See Figure 1	15		ns					
t <sub>PLH</sub> t <sub>PHL</sub>	V <sub>P</sub> , V <sub>M</sub> to D+, D– propagation delay	See Figure 4		17	ns					
t <sub>PLH</sub> t <sub>PHL</sub>	D+, D- to RCV propagation delay	See Figure 3		17	ns					
t <sub>PLH</sub> t <sub>PHL</sub>	D+, D– to $V_P$ , $V_M$ propagation delay	See Figure 3		10	ns					

<sup>(1)</sup> Specification for packaged product only

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Product Folder Link(s): TUSB2551



#### **TIMING DIAGRAMS**

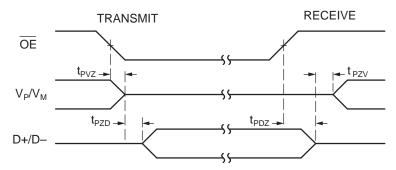


Figure 1. Enable and Disable Times



Figure 2. Rise and Fall Times

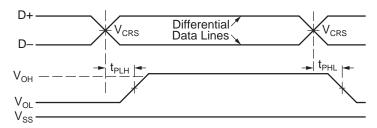


Figure 3. Receiver Propagation Delay

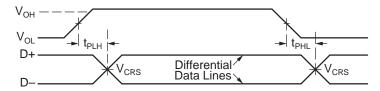


Figure 4. Driver Propagation Delay



#### **TEST CIRCUITS**

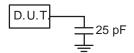


Figure 5. Load for  $V_P$ ,  $V_M$ , RCV

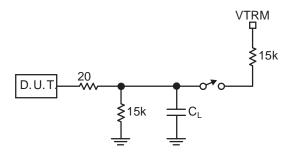


Figure 6. Load for D+, D-

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#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
TUSB2551PW	NRND	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TU2551	
TUSB2551PWG4	NRND	TSSOP	PW	14	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TU2551	
TUSB2551PWR	NRND	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TU2551	
TUSB2551PWRG4	NRND	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	TU2551	
TUSB2551RGTR	NRND	QFN	RGT	16	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ZWT	

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

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<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> Only one of markings shown within the brackets will appear on the physical device.



# **PACKAGE OPTION ADDENDUM**

24-Jan-2013

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

# **PACKAGE MATERIALS INFORMATION**

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## TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TUSB2551PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TUSB2551RGTR	QFN	RGT	16	3000	330.0	12.4	3.3	3.3	1.0	8.0	12.0	Q2

# **PACKAGE MATERIALS INFORMATION**

www.ti.com 26-Jan-2013



#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TUSB2551PWR	TSSOP	PW	14	2000	367.0	367.0	35.0
TUSB2551RGTR	QFN	RGT	16	3000	346.0	346.0	35.0

PW (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
  - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



# PW (R-PDSO-G14)

# PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



# RGT (S-PVQFN-N16) PLASTIC QUAD FLATPACK NO-LEAD 3,15 2,85 - A В 3,15 2,85 PIN 1 INDEX AREA TOP AND BOTTOM 0,20 REF. SEATING PLANE 0,08 0,05 0,00 Ċ 16 THERMAL PAD SIZE AND SHAPE SHOWN ON SEPARATE SHEET

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

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- B. This drawing is subject to change without notice.
- C. Quad Flatpack, No-leads (QFN) package configuration.

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- D. The package thermal pad must be soldered to the board for thermal and mechanical performance.
- E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.

16X  $\frac{0,30}{0,18}$ 

0,50

0,10 M C A B 0,05 M C

4203495/H 10/11

F. Falls within JEDEC MO-220.



# RGT (S-PVQFN-N16)

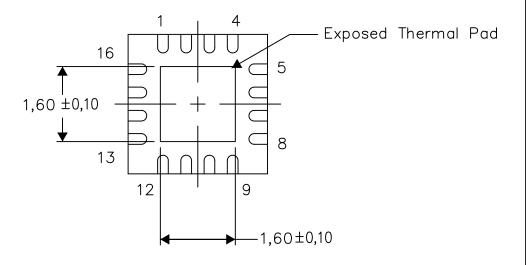
### PLASTIC QUAD FLATPACK NO-LEAD

#### THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

Exposed Thermal Pad Dimensions

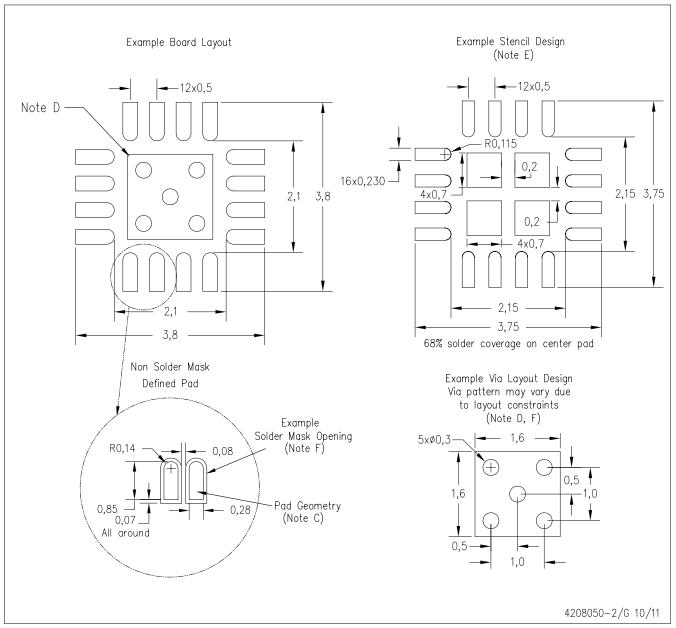
4206349-3/R 12/12

NOTE: All linear dimensions are in millimeters



# RGT (S-PVQFN-N16)

## PLASTIC QUAD FLATPACK NO-LEAD



#### NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <a href="https://www.ti.com">www.ti.com</a>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.



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